# MJD44E3, NJVMJD44E3T4G

# **Darlington Power Transistor**

## **DPAK For Surface Mount Applications**

Designed for general purpose power and switching output or driver stages in applications such as switching regulators, converters, and power amplifiers.

#### **Features**

- Electrically Similar to Popular D44E3 Device
- High DC Gain 1000 Min @ 5.0 Adc
- Low Sat. Voltage 1.5 V @ 5.0 Adc
- Compatible With Existing Automatic Pick and Place Equipment
- Epoxy Meets UL 94 V-0 @ 0.125 in
- ESD Ratings:
  - Human Body Model, 3B > 8000 V
  - Machine Model, C > 400 V
- NJV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These are Pb-Free Packages\*

#### **MAXIMUM RATINGS**

Rating	Symbol	Max	Unit
Collector-Emitter Voltage	V <sub>CEO</sub>	80	Vdc
Emitter-Base Voltage	V <sub>EB</sub>	7	Vdc
Collector Current - Continuous	I <sub>C</sub>	10	Adc
Total Power Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	P <sub>D</sub>	20 0.16	W W/°C
Total Power Dissipation (Note 1) @ T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	1.75 0.014	W W/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



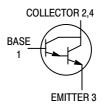
### ON Semiconductor®

http://onsemi.com

## NPN DARLINGTON SILICON POWER TRANSISTORS 10 AMPERES 80 VOLTS, 20 WATTS



DPAK CASE 369C STYLE 1



#### **MARKING DIAGRAM**



A = Assembly Location

Y = Year
WW = Work Week
J44E3 = Device Code
G = Pb-Free Package

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MJD44E3T4G	DPAK (Pb-Free)	2,500 / Tape & Reel
NJVMJD44E3T4G	DPAK (Pb-Free)	2,500 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

These ratings are applicable when surface mounted on the minimum pad sizes recommended.

<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

### MJD44E3, NJVMJD44E3T4G

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{ hetaJC}$	6.25	°C/W
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{ heta JA}$	71.4	°C/W
Lead Temperature for Soldering	TL	260	°C

<sup>2.</sup> These ratings are applicable when surface mounted on the minimum pad sizes recommended.

### ELECTRICAL CHARACTERISTICS (T<sub>C</sub> = 25°C unless otherwise noted)

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Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Collector Cutoff Current $(V_{CE} = Rated V_{CEO}, V_{BE} = 0)$	I <sub>CES</sub>	-	_	10	μΑ
Emitter Cutoff Current (V <sub>EB</sub> = 7 Vdc)	I <sub>EBO</sub>	-	_	1	μΑ
ON CHARACTERISTICS					
Collector–Emitter Saturation Voltage ( $I_C = 5$ Adc, $I_B = 10$ mAdc) ( $I_C = 10$ Adc, $I_B = 20$ mAdc)	V <sub>CE(sat)</sub>	- -	- -	1.5 2	Vdc
Base-Emitter Saturation Voltage (I <sub>C</sub> = 5 Adc, I <sub>B</sub> = 10 mAdc)	V <sub>BE(sat)</sub>	-	-	2.5	Vdc
DC Current Gain (V <sub>CE</sub> = 5 Vdc, I <sub>C</sub> = 5 Adc)	h <sub>FE</sub>	1000	-	-	_
DYNAMIC CHARACTERISTICS					
Collector Capacitance (V <sub>CB</sub> = 10 Vdc, f <sub>test</sub> = 1 MHz)	C <sub>cb</sub>	-	-	130	pF
SWITCHING TIMES					
Delay and Rise Times (I <sub>C</sub> = 10 Adc, I <sub>B1</sub> = 20 mAdc)	t <sub>d</sub> + t <sub>r</sub>	-	0.6	-	μs
Storage Time (I <sub>C</sub> = 10 Adc, I <sub>B1</sub> = I <sub>B2</sub> = 20 mAdc)	t <sub>s</sub>	-	2	-	μs
Fall Time (I <sub>C</sub> = 10 Adc, I <sub>B1</sub> = I <sub>B2</sub> = 20 mAdc)	t <sub>f</sub>	-	0.5	-	μs

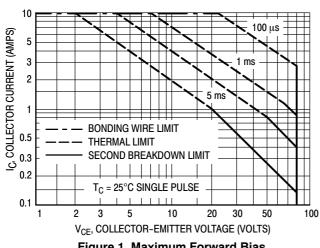


Figure 1. Maximum Forward Bias Safe Operating Area

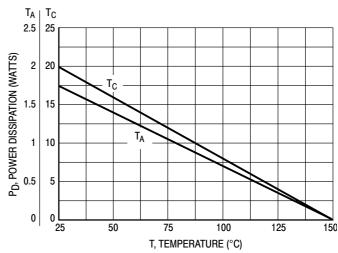
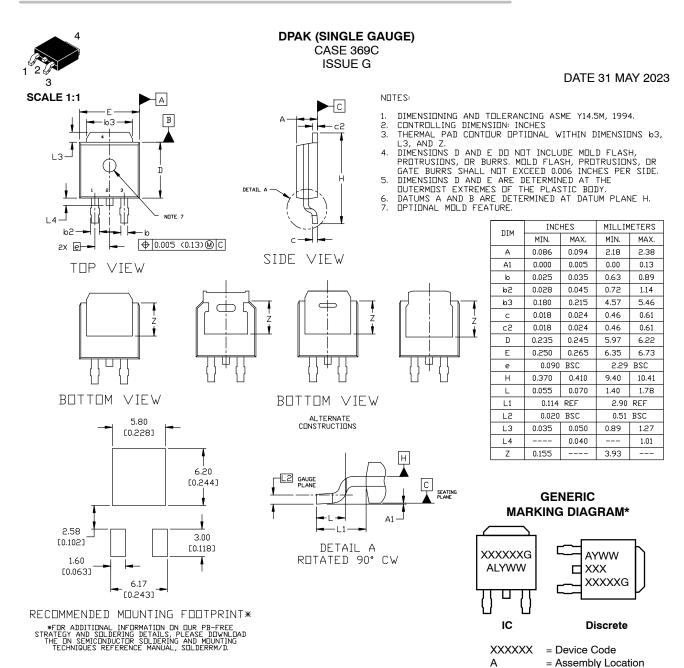


Figure 2. Power Derating





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L	= Wafer Lot	
STYLE 1:         STYLE 2:         STYLE 3:         STYLE 4:         STYLE 5:         Y           PIN 1. BASE         PIN 1. GATE         PIN 1. ANODE         PIN 1. CATHODE         PIN 1. GATE         WW           2. COLLECTOR         2. DRAIN         2. CATHODE         2. ANODE         2. ANODE         2. ANODE           3. EMITTER         3. SOURCE         3. ANODE         3. GATE         3. CATHODE         G           4. COLLECTOR         4. DRAIN         4. CATHODE         4. ANODE         4. ANODE         4. ANODE	= Year = Work Week = Pb-Free Package	

\*This information is generic. Please refer to STYLE 7: PIN 1. GATE 2. COLLECTOR device data sheet for actual part marking. STYLE 6: STYLE 8: STYLE 9: STYLE 10: PIN 1. CATHODE 2. ANODE 3. CATHODE PIN 1. MT1 2. MT2 PIN 1. ANODE 2. CATHODE Pb-Free indicator, "G" or microdot "■", may PIN 1. N/C 2. CATHODE or may not be present. Some products may 3 ANODE 3 RESISTOR ADJUST 3 GATE 3 FMITTER not follow the Generic Marking. 4. COLLECTOR CATHODE 4. ANODE CATHODE

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DESCRIPTION:	DPAK (SINGLE GAUGE)		PAGE 1 OF 1

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